# 74HC4094-Q100; 74HCT4094-Q100

8-stage shift-and-store bus register

Rev. 4 — 21 March 2024

Product data sheet

# 1. General description

The 74HC4094-Q100; 74HCT4094-Q100 is an 8-bit serial-in/serial or parallel-out shift register with a storage register and 3-state outputs. Both the shift and storage register have separate clocks. The device features a serial input (D) and two serial outputs (QS1 and QS2) to enable cascading. Data is shifted on the LOW-to-HIGH transitions of the CP input. Data is available at QS1 on the LOW-to-HIGH transitions of the CP input to allow cascading when clock edges are fast. The same data is available at QS2 on the next HIGH-to-LOW transition of the CP input to allow cascading when clock edges are slow. The data in the shift register is transferred to the storage register when the STR input is HIGH. Data in the storage register appears at the outputs whenever the output enable input (OE) is HIGH. A LOW on OE causes the outputs to assume a high-impedance OFF-state. Operation of the OE input does not affect the state of the registers. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{\rm CC}$ .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Complies with JEDEC standard JESD7A
- Input levels:
  - For 74HC4094-Q100: CMOS level
  - For 74HCT4094-Q100: TTL level
- · Low-power dissipation
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

# 3. Applications

- Serial-to-parallel data conversion
- · Remote control holding register

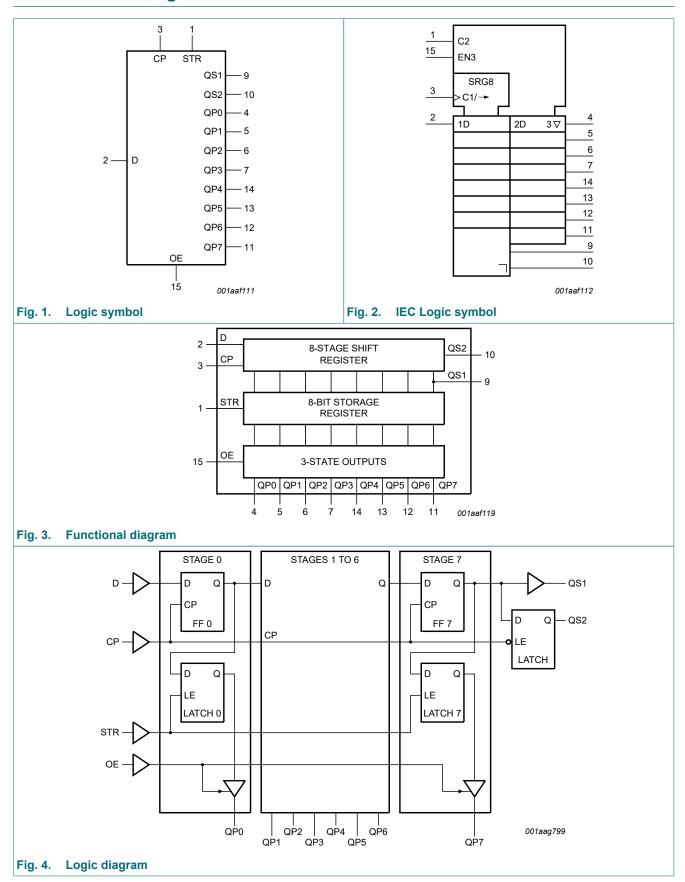
# 4. Ordering information

#### **Table 1. Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
74HC4094D-Q100 74HCT4094D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC4094PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

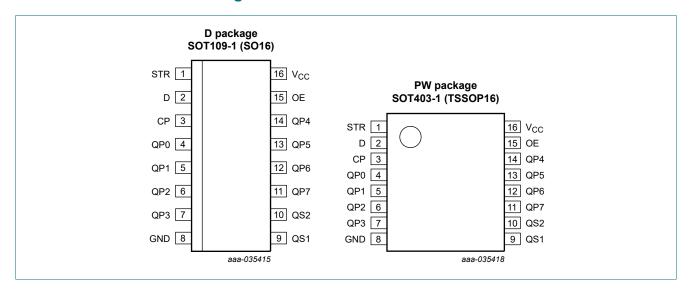


# 5. Functional diagram



# 6. Pinning information

## 6.1. Pinning



# 6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
STR	1	strobe input
D	2	data input
СР	3	clock input
QP0, QP1, QP2, QP3, QP4, QP5, QP6, QP7	4, 5, 6, 7, 14, 13, 12, 11	parallel output
GND	8	ground supply voltage
QS1, QS2	9, 10	serial output
OE	15	output enable input
V <sub>CC</sub>	16	supply voltage

# 7. Functional description

#### **Table 3. Function table**

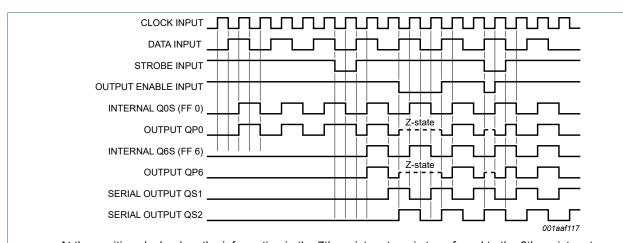
H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = HIGH-impedance OFF-state; NC = no change;

 $\uparrow$  = positive-going transition;  $\downarrow$  = negative-going transition;

Q6S = the data in register stage 6 before the LOW to HIGH clock transition;

Q7S = the data in register stage 7 before the HIGH to LOW clock transition.

Inputs					outputs	Serial out	Serial outputs		
CP OE STR D		QP0	QPn	QS1	QS2				
<b>↑</b>	L	X	Х	Z	Z	Q6S	NC		
Ţ	L	X	Х	Z	Z	NC	Q7S		
1	Н	L	Х	NC	NC	Q6S	NC		
1	Н	Н	L	L	QPn -1	Q6S	NC		
1	Н	Н	Н	Н	QPn -1	Q6S	NC		
<b>↓</b>	Н	Н	Н	NC	NC	NC	Q7S		



At the positive clock edge, the information in the 7th register stage is transferred to the 8th register stage and the QSn outputs.

Fig. 5. Timing diagram

# 8. Limiting values

### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_1 < -0.5 \text{ V or } V_1 > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	$V_O = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-	-50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	[1]	-	500	mW

<sup>[1]</sup> For SOT109-1 (SO16) package:  $P_{tot}$  derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package:  $P_{tot}$  derates linearly with 8.5 mW/K above 91 °C.

# 9. Recommended operating conditions

### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74H	C4094-C	100	74H	Unit		
			Min	Тур	Max	Min	Тур	Max	
$V_{CC}$	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

# 10. Static characteristics

### **Table 6. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC409	94-Q100		'					1	<u>'</u>	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND};$ $V_{CC} = 6.0 \text{ V}$	-	-	±0.5	-	±5.0	-	±10.0	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT4	094-Q100						·	1	<b>'</b>	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.5	-	±5.0	-	±10	μΑ
I <sub>CC</sub>	supply current	$V_1 = V_{CC}$ or GND; $I_0 = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_I = V_{CC}$ - 2.1 V; other inputs at $V_{CC}$ or GND; $V_{CC}$ = 4.5 V to 5.5 V; $I_O$ = 0 A								
		per input pin; STR input	-	100	360	-	450	-	490	μA
		per input pin; OE input	-	150	540	-	675	-	735	μΑ
		per input pin; CP input	-	150	540	-	675	-	735	μΑ
		per input pin; D input	-	40	144	-	180	-	196	μΑ
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF

# 11. Dynamic characteristics

### **Table 7. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V);  $C_L$  = 50 pF unless otherwise specified; for test circuit see Fig. 10.

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC40	94-Q100					-		1	-	
t <sub>pd</sub>	propagation	CP to QS1; see Fig. 6 [1]								
	delay	V <sub>CC</sub> = 2.0 V	-	50	150	-	190	-	225	ns
		V <sub>CC</sub> = 4.5 V	-	18	30	-	38	-	45	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	15	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	26	-	33	-	38	ns
		CP to QS2; see Fig. 6 [1]								
		V <sub>CC</sub> = 2.0 V	-	44	135	-	170	-	205	ns
		V <sub>CC</sub> = 4.5 V	-	16	27	-	34	-	41	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	13	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	13	23	-	29	-	35	ns
		CP to QPn; see Fig. 6 [1]								
		V <sub>CC</sub> = 2.0 V	-	63	195	-	245	-	295	ns
		V <sub>CC</sub> = 4.5 V	-	23	39	-	49	-	59	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	20	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	18	33	-	42	-	50	ns
		STR to QPn; see Fig. 7 [1]								
		V <sub>CC</sub> = 2.0 V	-	58	180	-	225	-	270	ns
		V <sub>CC</sub> = 4.5 V	-	21	36	-	45	-	54	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	18	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	17	31	-	38	-	46	ns
t <sub>en</sub>	enable time	OE to QPn; see Fig. 8 [1]								
		V <sub>CC</sub> = 2.0 V	-	55	175	-	220	-	265	ns
		V <sub>CC</sub> = 4.5 V	-	20	35	-	44	-	53	ns
		V <sub>CC</sub> = 6.0 V	-	16	30	-	37	-	45	ns
t <sub>dis</sub>	disable time	OE to QPn; see Fig. 8 [1]								
		V <sub>CC</sub> = 2.0 V	-	41	125	-	155	-	190	ns
		V <sub>CC</sub> = 4.5 V	-	15	25	-	31	-	38	ns
		V <sub>CC</sub> = 6.0 V	-	12	21	-	26	-	32	ns
t <sub>t</sub>	transition	QPn and QSn; see Fig. 6 [1]								
	time	V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns

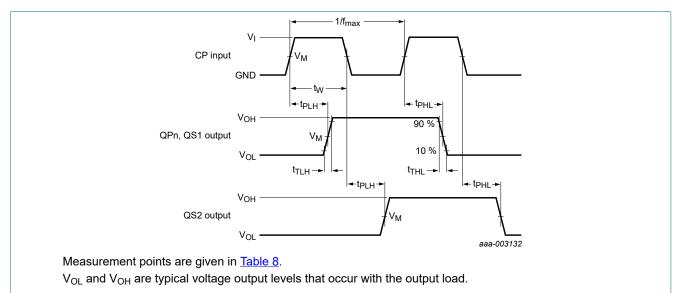
Symbol Parame	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>W</sub>	pulse width	CP HIGH or LOW; see Fig. 6								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
		STR HIGH; see Fig. 7								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
t <sub>su</sub>	set-up time	D to CP; see Fig. 9								
		V <sub>CC</sub> = 2.0 V	50	14	-	65	-	75	-	ns
		V <sub>CC</sub> = 4.5 V	10	5	-	13	-	15	-	ns
		V <sub>CC</sub> = 6.0 V	9	4	-	11	-	13	-	ns
		CP to STR; see Fig. 7								
		V <sub>CC</sub> = 2.0 V	100	28	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	10	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	8	-	21	-	26	-	ns
t <sub>h</sub>	hold time	D to CP; see Fig. 9								
		V <sub>CC</sub> = 2.0 V	3	-6	-	3	-	3	-	ns
		V <sub>CC</sub> = 4.5 V	3	-2	-	3	-	3	-	ns
		V <sub>CC</sub> = 6.0 V	3	-2	-	3	-	3	-	ns
		CP to STR; see Fig. 7								
		V <sub>CC</sub> = 2.0 V	0	-14	-	0	-	0	-	ns
		V <sub>CC</sub> = 4.5 V	0	-5	-	0	-	0	-	ns
		V <sub>CC</sub> = 6.0 V	0	-4	-	0	-	0	-	ns
f <sub>max</sub>	maximum	CP; see Fig. 6								
	frequency	V <sub>CC</sub> = 2.0 V	6.0	28	-	4.8	-	4.0	-	MHz
		V <sub>CC</sub> = 4.5 V	30	87	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	95	-	-	-	-	-	MHz
		V <sub>CC</sub> = 6.0 V	35	103	-	28	-	24	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$C_L = 50 \text{ pF; } f = 1 \text{ MHz;}$ [2] $V_I = \text{GND to } V_{CC}$	-	83	-	-	-	-	-	pF

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
74HCT4	094-Q100								-	<u>'</u>	'
t <sub>pd</sub>	propagation	CP to QS1; see Fig. 6	[1]								
	delay	V <sub>CC</sub> = 4.5 V		-	23	39	-	49	-	59	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	19	-	-	-	-	-	ns
		CP to QS2; see Fig. 6	[1]								
		V <sub>CC</sub> = 4.5 V		-	21	36	-	45	-	54	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	18	-	-	-	-	-	ns
		CP to QPn; see Fig. 6	[1]								
		V <sub>CC</sub> = 4.5 V		-	25	43	-	54	-	65	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	21	-	-	-	-	-	ns
		STR to QPn; see Fig. 7	[1]								
		V <sub>CC</sub> = 4.5 V		-	22	39	-	49	-	59	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	19	-	-	-	-	-	ns
t <sub>en</sub>	enable time	OE to QPn; see Fig. 8	[1]								
		V <sub>CC</sub> = 4.5 V		-	20	35	-	44	-	53	ns
t <sub>dis</sub>	disable time	OE to QPn; see Fig. 8	[1]								
		V <sub>CC</sub> = 4.5 V		-	21	35	-	44	-	53	ns
t <sub>t</sub>	transition	QPn and QSn; see Fig. 6	[1]								
	time	V <sub>CC</sub> = 4.5 V		-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	CP HIGH or LOW; see Fig. 6									
		V <sub>CC</sub> = 4.5 V		16	7	-	20	-	24	-	ns
		STR HIGH; see Fig. 7									
		V <sub>CC</sub> = 4.5 V		16	5	-	20	-	24	-	ns
t <sub>su</sub>	set-up time	Dn to CP; see Fig. 9									
		V <sub>CC</sub> = 4.5 V		10	4	-	13	-	15	-	ns
		CP to STR; see Fig. 7									
		V <sub>CC</sub> = 4.5 V		20	9	-	25	-	30	-	ns
t <sub>h</sub>	hold time	Dn to CP; see Fig. 9									
		V <sub>CC</sub> = 4.5 V		4	0	-	4	-	4	-	ns
		CP to STR; see Fig. 7									
		V <sub>CC</sub> = 4.5 V		0	-4	-	0	-	0	-	ns
f <sub>max</sub>	maximum	CP; see Fig. 6									
	frequency	V <sub>CC</sub> = 4.5 V		30	80	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	86	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$C_L$ = 50 pF; f = 1 MHz; $V_I$ = GND to $V_{CC}$ - 1.5 V	[2]	-	92	-	-	-	-	-	pF

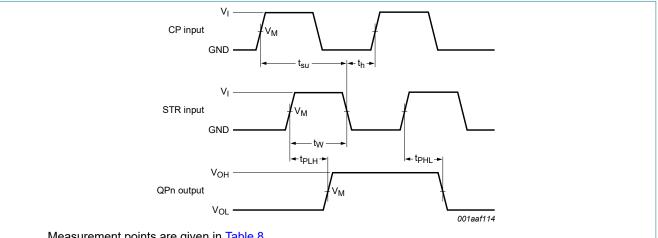
t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>; t<sub>en</sub> is the same as t<sub>PZH</sub> and t<sub>PZL</sub>; t<sub>dis</sub> is the same as t<sub>PLZ</sub> and t<sub>PHZ</sub>; t<sub>t</sub> is the same as t<sub>THL</sub> and t<sub>TLH</sub>.
 C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).
 P<sub>D</sub> = C<sub>PD</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>i</sub> × N + ∑(C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) where:

 $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;  $C_L$  = output load capacitance in pF;  $V_{CC}$  = supply voltage in V; N = number of inputs switching;  $\sum (C_L \times V_{CC})^2 \times f_o$  = sum of outputs.

### 11.1. Waveforms and test circuits



Propagation delay input (CP) to output (QPn, QS1, QS2), output transition time, clock input (CP) pulse Fig. 6. width and the maximum frequency (CP)



Measurement points are given in Table 8.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Propagation delay strobe input (STR) to output (QPn), strobe input (STR) pulse width and the clock set-up Fig. 7. and hold times for strobe input

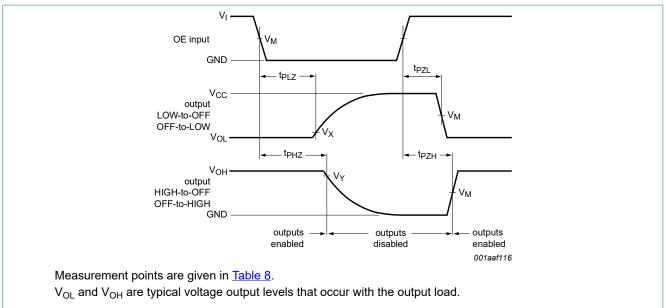
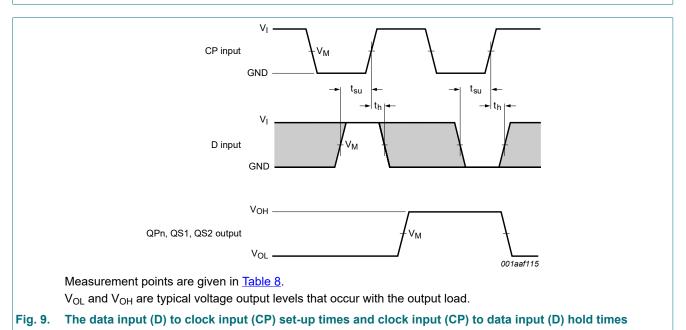
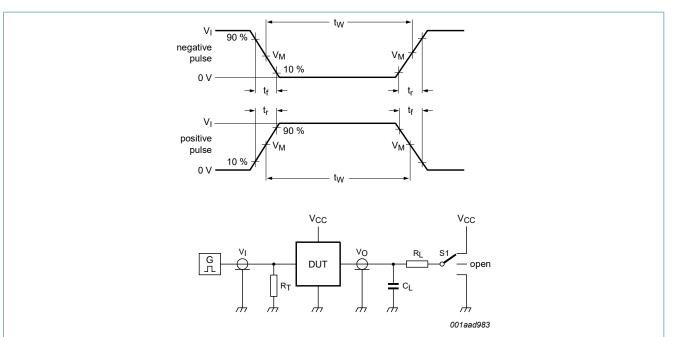


Fig. 8. Enable and disable times



**Table 8. Measurement points** 

Туре	Input	Output		
	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
74HC4094-Q100	0.5 × V <sub>CC</sub>	0.5 × V <sub>CC</sub>	0.1 × V <sub>OH</sub>	0.9 × V <sub>OH</sub>
74HCT4094-Q100	1.3 V	1.3 V	0.1 × V <sub>OH</sub>	0.9 × V <sub>OH</sub>



Test data is given in Table 9.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

R<sub>I</sub> = Load resistance;

S1 = Test selection switch.

Fig. 10. Test circuit for measuring switching times

Table 9. Test data

Туре	Input		Load		S1 position			
	$V_{l}$	t <sub>r</sub> , t <sub>f</sub>	CL	$R_L$	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>	
74HC4094-Q100	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>	
74HCT4094-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>	

# 12. Package outline

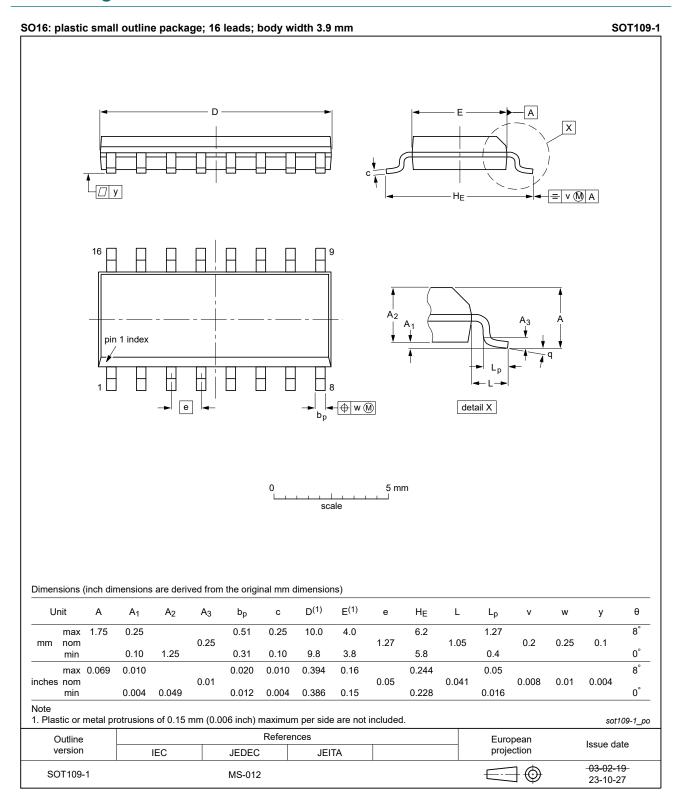


Fig. 11. Package outline SOT109-1 (SO16)

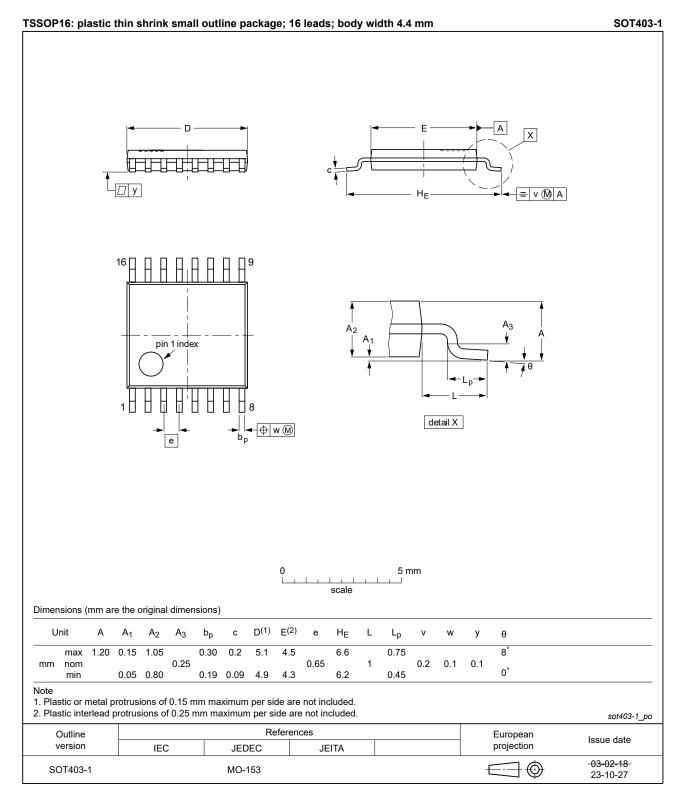


Fig. 12. Package outline SOT403-1 (TSSOP16)

# 13. Abbreviations

### **Table 10. Abbreviations**

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

# 14. Revision history

### **Table 11. Revision history**

Table 11. Nevision instory							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT4094_Q100 v.4	20240321	Product data sheet	-	74HC_HCT4094_Q100 v.3			
Modifications:	<ul> <li>Fig. 11, Fig. 12: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153.</li> <li>Section 2: ESD specification updated according to the latest JEDEC standard.</li> </ul>						
74HC_HCT4094_Q100 v.3	20211022	Product data sheet	-	74HC_HCT4094_Q100 v.2			
Modifications:	<ul> <li>Type numbers 74HC4094DB-Q100 and 74HCT4094DB-Q100 (SOT338-1/SSOP16) removed.</li> <li>Section 8: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul>						
74HC_HCT4094_Q100 v.2	20181114	Product data sheet	-	74HC_HCT4094_Q100 v.1			
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Fig. 4 and Fig. 5 corrected.</li> </ul>						
74HC_HCT4094_Q100 v.1	20130130	Product data sheet	-	-			

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Product data sheet

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For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 21 March 2024

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